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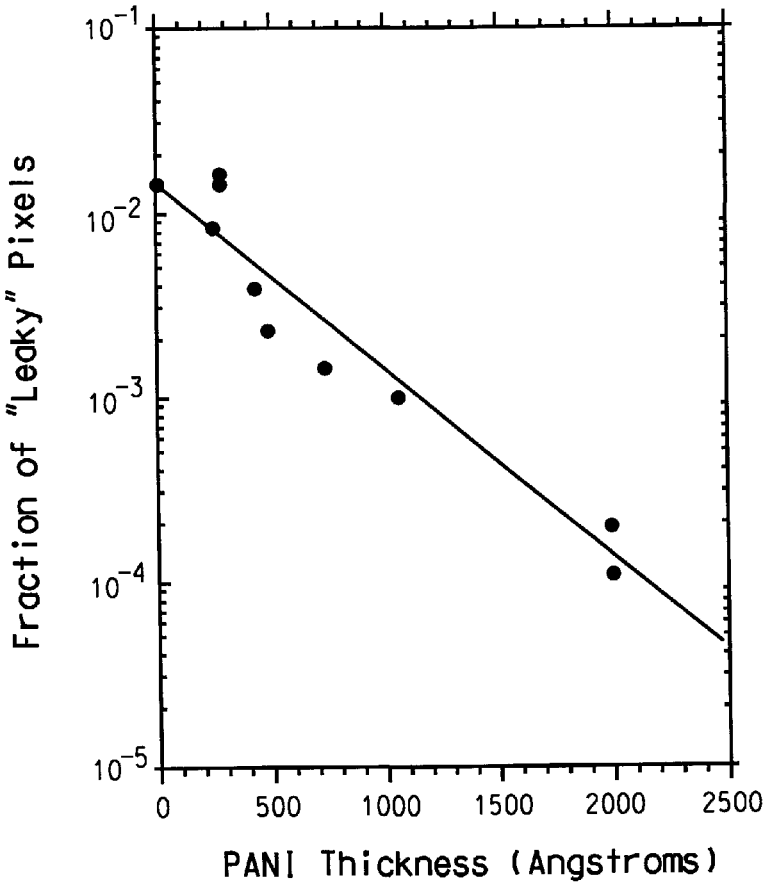
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(54) Title: HIGH RESISTANCE CONDUCTIVE POLYMERS FOR USE IN HIGH EFFICIENCY PIXELLATED ORGANIC ELECTRONIC DEVICES



(57) Abstract: In pixellated electronic devices such as polymer emissive displays (PEDs), good operating lifetime is achieved through the use of a high resistivity buffer layer of conductive organic polymer between the anode layer and the photoactive layer. The improved high resistivity conductive layer gives long lifetime with reduced or no cross-talk and current leakage between neighboring pixels.

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